NSN 5961-01-240-0454

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Internal Configuration:
Field effect-dual gate
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 drain to source voltage
Current Rating Per Characteristic:
30.00 milliamperes drain current and 10.00 milliamperes gate 1 current and 10.00 milliamperes gate 2 current
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0